

R3116x Series

0.8% Low Voltage Detector with Output Delay

NO.EA-161-140819

OUTLINE

The R3116x series are CMOS-based voltage detector ICs with high detector threshold accuracy and ultra-low supply current, which can be operated at an extremely low voltage and is used for system reset as an example.

Each of these ICs consists of a voltage reference unit, a comparator, resistors for detector threshold setting, an output driver, a hysteresis circuit and an output delay circuit. The detector threshold is internally fixed with high accuracy and does not require any adjustment.

Two output types, Nch open drain type and CMOS type are available.

The R3116x series are operable at a lower voltage than that of the R3112x series, and can be driven by a single battery.

Three types of packages, SOT-23-5, SC-82AB, and DFN(PLP)1010-4 are available.

FEATURES

Supply Current	Τyp. 0.35μA (-Vdet=1.5V, Vdd=-Vdet+1V)
Operating Voltage Range	0.5V to 6.0V (Topt=25°C)
Detector Threshold Range	0.7V to 5.0V (0.1V step)
Detector Threshold Accuracy	±0.8% (-Vdet ≥ 1.5V)
Temperature-Drift Coefficient of Detector Threshold	Typ. ±30ppm/°C
Built-in Output Delay Circuit	Typ. 100ms with an external capacitor: 0.022µF
Output Delay Time Accuracy	±15% (-Vdet ≥ 1.5V)
Output Types	Nch Open Drain "L" and CMOS
Packages	DFN(PLP)1010-4, SC-82AB, SOT-23-5

APPLICATIONS

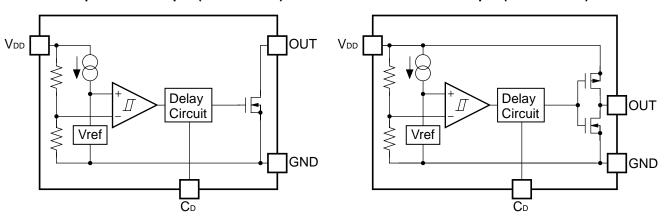
- CPU and Logic Circuit Reset
- · Battery Checker
- Window Comparator
- · Wave Shaping Circuit
- Battery Back-up Circuit
- Power Failure Detector

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BLOCK DIAGRAMS

Nch Open Drain Output (R3116xxx1A)

CMOS Output (R3116xxx1C)



SELECTION GUIDE

The package type, the detector threshold, the output type and the taping type for the ICs can be selected at the users' request.

Product Name	Package	Quantity per Reel	Pb Free	Halogen Free
R3116Kxx1*-TR	DFN(PLP)1010-4	10,000 pcs	Yes	Yes
R3116Qxx1*-TR-FE	SC-82AB	3,000 pcs	Yes	Yes
R3116Nxx1*-TR-FE	SOT-23-5	3,000 pcs	Yes	Yes

xx: The detector threshold can be designated in the range from 0.7V(07) to 5.0V(50) in 0.1V step.

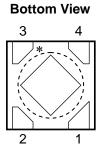
- * : Designation of Output Type
 - (A) Nch Open Drain
 - (C) CMOS

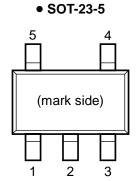
PIN DESCRIPTIONS

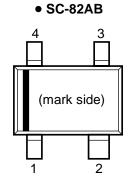
• DFN(PLP)1010-4

Top View
4 3

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• DFN(PLP)1010-4

Pin No.	Symbol	Description
1	OUT	Output Pin ("L" at detection)
2	С□	Pin for External Capacitor (for setting output delay)
3	GND	Ground Pin
4	V _{DD}	Input Pin

*) Tab is GND level. (They are connected to the reverse side of this IC.)

The tab is better to be connected to the GND, but leaving it open is also acceptable.

• SOT-23-5

Pin No.	Symbol	Description
1	OUT	Output Pin ("L" at detection)
2	V_{DD}	Input Pin
3	GND	Ground Pin
4	NC	No Connection
5	С	Pin for External Capacitor (for setting output delay)

• SC-82AB

Pin No.	Symbol	Description
1	V_{DD}	Input Pin
2	GND	Ground Pin
3	С□	Pin for External Capacitor (for setting output delay)
4	OUT	Output Pin ("L" at detection)

NO.EA-161-140819

ABSOLUTE MAXIMUM RATINGS

Symbol	Item	Rating	Unit
V _{DD}	Supply Voltage	7.0	V
Vоит	Output Voltage (Nch Open Drain Output)	Vss-0.3 to 7.0	V
VOUT	Output Voltage (CMOS Output)	Vss-0.3 to VDD+0.3	V
louт	Output Current	20	mA
	Power Dissipation (SOT-23-5)*	420	
PD	Power Dissipation (SC-82AB)*	380	mW
	Power Dissipation (DFN(PLP)1010-4)*	400	
Topt	Operating Temperature Range	-40 to 85	°C
Tstg	Storage Temperature Range	-55 to 125	°C

^{*} Please refer to PACKAGE INFORMATION for detailed information.

ABSOLUTE MAXIMUM RATINGS

Electronic and mechanical stress momentarily exceeded absolute maximum ratings may cause the permanent damages and may degrade the life time and safety for both device and system using the device in the field. The functional operation at or over these absolute maximum ratings is not assured.

RECOMMENDED OPERATING CONDITIONS (ELECTRICAL CHARACTERISTICS)

All of electronic equipment should be designed that the mounted semiconductor devices operate within the recommended operating conditions. The semiconductor devices cannot operate normally over the recommended operating conditions, even if when they are used over such conditions by momentary electronic noise or surge. And the semiconductor devices may receive serious damage when they continue to operate over the recommended operating conditions.

ELECTRICAL CHARACTERISTICS

• R3116xxx1A/C values indicate $-40^{\circ}C \le T_{opt} \le 85^{\circ}C$, unless otherwise noted. (Topt=25°C)

Symbol	Item	Conditions			Min.	Тур.	Max.	Unit		
		Topt=25	5°C		1.5V <	< -V _{DET} ≤ 5.0V	-V _{DET} × 0.992		-V _{DET} ×1.008	V
-V _{DET}	Detector Threshold	,			0.7V ≤	≤ - V _{DET} ≤ 1.5 V	-12		+12	mV
-VDET	Detector Threshold	–40°C ≤	≤ Topt ≤ 85	5°C	1.5V <	$<$ -VDET ≤ 5.0 V	-V _{DET} × 0.985		-V _{DET} × 1.015	V
			-		0.7V ≤	\leq -VDET \leq 1.5V	-22.5		+22.5	mV
V _H ys	Detector Threshold Hysteresis						-V _{DET} × 0.04		-V _{DET} × 0.07	٧
					0.7V ≤	≤ -V DET < 1.6V			1.400	
		\/\/-	DET -0.1V		1.6V ≤	≤ - Vdet < 3.1V			1.500	
		v bb= - v l	DEI - U.IV		3.1V ≤	≤ - V _{DET} < 4.1V			1.600	
Iss	Supply Current				4.1V ≤	≤ -V DET ≤ 5.0V			1.700	μΑ
155	Supply Current				0.7V ≤	≤ -V DET < 1.6V			1.200	μΑ
		VDD=-VDET +1.0V			1.6V ≤	≤ - V _{DET} < 3.1V			1.200	
					3.1V ≤	≤ - V _{DET} < 4.1V			1.300	
				$4.1V \le -V_{DET} \le 5.0V$		\leq -VDET \leq 5.0V			1.400	
VDDH	Maximum Operating Voltage							6	V	
V _{DDL}	Minimum Operating	Topt=25°C						0.50	V	
V DDL	Voltage*1	-40°C ≤	\leq Topt \leq 85	5°C					0.55	V
			V _{DD} =0.55	V, Vds=	0.05V		7			μΑ
			0.7V ≤ - V	DET < 1.1	V VD	D=0.6V, VDS=0.5V	0.020			
		Nch	$1.1V \le -V_{DET} < 1.6V$ $V_{DD}=1.0V, V_{DS}=0.5V$		0.400			mA		
Іоит	Output Current (Driver Output Pin)		1.6V ≤ -V _{DET} < 3.1		V VD	D=1.5V, VDS=0.5V	1.000			
	(=,		$3.1V \le -V_{DET} \le 5.0V$ $V_{DD}=3.0V$,		D=3.0V, VDS=0.5V	2.400				
		Pch*2	0.7V ≤ - V	DET < 4.0	.0V V _{DD} =4.5V, V _{DS} =-2.1V		0.650			mΛ
		Pcn ⁻²	4.0V ≤ -V	DET ≤ 5.0	V VDI	=6.0V, V _{DS} =-2.1V	0.900			mA
ILEAK	Nch Driver Leakage Current*3	V _{DD} =6.0V, V _{DS} =7.0V						80	nA	
Δ-V _{DET} / ΔTopt	Detector Threshold Temperature Coefficient					±30		ppm /°C		
				Topt=2	5°C	0.7V ≤ -VDET < 1.5V	80	100	130	
t ⊳	Output Delay Time	C _D =0.02	22μF _{DET} –0.1V	i opt=2	.5 C	$1.5V \le -V_{DET} \le 5.0V$		100	115	ms
LD LD	Output Delay Tillie		T × 1.1V	-40°C		0.7V ≤ -VDET < 1.5V		100	150	1113
		Topt		Topt ≤	85°C	$1.5V \le -V_{DET} \le 5.0V$	75	1.00	135	

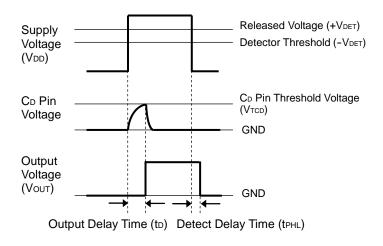
All of unit are tested and specified under load conditions such that Topt=25°C except for Detector Threshold Temperature Coefficient.

RICOH

^{*1:} Minimum operating voltage means the value of input voltage when output voltage maintains 0.1V or less. (In case of Nch Open Drain Output type, the output pin is pulled up with a resistance of $470k\Omega$ to 5.0V)

^{*2:} In case of CMOS type
*3: In case of Nch Open Drain type

TIMING CHART



When the supply voltage, which is higher than released voltage, is forced to V_{DD} pin, charge to an external capacitor starts, then C_{D} pin voltage increases. Until the C_{D} pin voltage reaches to C_{D} pin threshold voltage, output voltage maintains "L". When the C_{D} pin voltage becomes higher than C_{D} pin threshold voltage, output voltage is reversed from "L" to "H". Where the time interval between the rising edge of supply voltage and output voltage reverse point means output delay time.

When the output voltage reverses from "L" to "H", the external capacitor starts to discharge. Therefore, when lower voltage than the detector threshold voltage is forced to V_{DD} pin, the output voltage reverses from "H" to "L" thus the detect delay time is constant not being affected by the external capacitor.

Output Delay Time

Output Delay Time (t_D) can be calculated with the next formula using the external capacitor: $t_D(s) = 4.5 \times 10^6 \times C_D(F)$

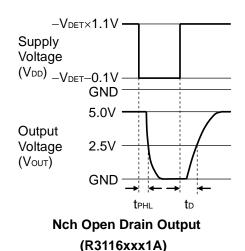
DEFINITION OF OUTPUT DELAY TIME

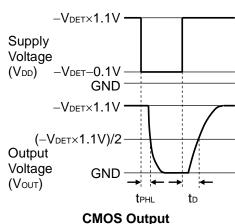
Output Delay Time (to) is defined as follows:

In the case of Nch Open Drain Output:
 Under the condition of the output pin (OUT) is pulled up through a resistor of 470kΩ to 5V, the time interval between the rising edge of V_{DD} pulse from (-V_{DET})-0.1V to (-V_{DET})×1.1V pulse voltage is supplied, the becoming of the output voltage to 2.5V.

2. In the case of CMOS Output:

The time interval between the rising edge of V_{DD} pulse from $(-V_{DET})-0.1V$ to $(-V_{DET})\times1.1V$ pulse voltage is supplied, the becoming of the output voltage to $((-V_{DET})\times1.1V)/2$.





(R3116xxx1C)

ELECTRICAL CHARACTERISTICS BY DETECTOR THRESHOLD

• R3116x071A/C to R3116x501A/C

Bold values are checked and guaranteed by design engineering at −40°C ≤ Topt ≤ 85°C, unless otherwise noted.

(Topt=25°C)

Part		ector shold1		ector hold2		Threshold eresis	Supply	Current1	Supply (Current2	Max. Op. Voltage	Min. Op. Voltage
Number	-V DE	T1 [V]	-VDE	г2 [V]	VHY	s [V]	Issı [µA]		ss1 [µA] Iss2 [µA]		VDDH [V]	VDDL [V]
	Min.	Max.	Min.	Max.	Min.	Max.	Cond.	Max.	Cond.	Max.	Max.	Max.
R3116x071A/C	0.688	0.712	0.678	0.723	0.028	0.049						
R3116x081A/C	0.788	0.812	0.778	0.823	0.032	0.056						
R3116x091A/C	0.888	0.912	0.878	0.923	0.036	0.063						
R3116x101A/C	0.988	1.012	0.978	1.023	0.040	0.070						
R3116x111A/C	1.088	1.112	1.078	1.123	0.044	0.077		1.400				
R3116x121A/C	1.188	1.212	1.178	1.223	0.048	0.084						
R3116x131A/C	1.288	1.312	1.278	1.323	0.052	0.091						
R3116x141A/C	1.388	1.412	1.378	1.423	0.056	0.098						
R3116x151A/C	1.488	1.512	1.478	1.523	0.060	0.105						
R3116x161A/C	1.587	1.613	1.576	1.624	0.064	0.112						
R3116x171A/C	1.686	1.714	1.675	1.726	0.068	0.119						
R3116x181A/C	1.786	1.814	1.773	1.827	0.072	0.126				1.200		
R3116x191A/C	1.885	1.915	1.872	1.929	0.076	0.133				1.200		
R3116x201A/C	1.984	2.016	1.970	2.030	0.080	0.140						
R3116x211A/C	2.083	2.117	2.069	2.132	0.084	0.147						
R3116x221A/C	2.182	2.218	2.167	2.233	0.088	0.154						
R3116x231A/C	2.282	2.318	2.266	2.335	0.092	0.161		1.500				
R3116x241A/C	2.381	2.419	2.364	2.436	0.096	0.168						
R3116x251A/C	2.480	2.520	2.463	2.538	0.100	0.175						0.50
R3116x261A/C	2.579	2.621	2.561	2.639	0.104	0.182						0.50
R3116x271A/C	2.678	2.722	2.660	2.741	0.108	0.189	\/		\/			
R3116x281A/C	2.778	2.822	2.758	2.842	0.112	0.196	VDD=		VDD=		C	0.55
R3116x291A/C	2.877	2.923	2.857	2.944	0.116	0.203	-VDET -0.1V		-VDET +1.0V		6	0.55
R3116x301A/C	2.976	3.024	2.955	3.045	0.120	0.210	-0.10		+1.00			
R3116x311A/C	3.075	3.125	3.054	3.147	0.124	0.217					1	*Note1
R3116x321A/C	3.174	3.226	3.152	3.248	0.128	0.224						*INOLE I
R3116x331A/C	3.274	3.326	3.251	3.350	0.132	0.231						
R3116x341A/C	3.373	3.427	3.349	3.451	0.136	0.238						
R3116x351A/C	3.472	3.528	3.448	3.553	0.140	0.245		4 000		4 000		
R3116x361A/C	3.571	3.629	3.546	3.654	0.144	0.252		1.600		1.300		
R3116x371A/C	3.670	3.730	3.645	3.756	0.148	0.259						
R3116x381A/C	3.770	3.830	3.743	3.857	0.152	0.266						
R3116x391A/C	3.869	3.931	3.842	3.959	0.156	0.273						
R3116x401A/C	3.968	4.032	3.940	4.060	0.160	0.280						
R3116x411A/C	4.067	4.133	4.039	4.162	0.164	0.287			1		1	
R3116x421A/C	4.166	4.234	4.137	4.263	0.168	0.294						
R3116x431A/C	4.266	4.334	4.236	4.365	0.172	0.301						
R3116x441A/C	4.365	4.435	4.334	4.466	0.176	0.308						
R3116x451A/C	4.464	4.536	4.433	4.568	0.180	0.315		4 700		4 405		
R3116x461A/C	4.563	4.637	4.531	4.669	0.184	0.322		1.700		1.400		
R3116x471A/C	4.662	4.738	4.630	4.771	0.188	0.329						
R3116x481A/C	4.762	4.838	4.728	4.872	0.192	0.336						
R3116x491A/C	4.861	4.939	4.827	4.974	0.196	0.343						
R3116x501A/C	4.960	5.040	4.925	5.075	0.200	0.350						

^{*}Note1) V_{DD} value when output voltage is equal or less than 0.1V. In the case of Nch Open Drain output type, the output pin is pulled up to 5.0V through 470k Ω resistor.

Curr	er Output ent1	Curr	er Output ent2	Cur	er Output rent	Leakage	Oriver Current	Detector Threshold Temperature Coefficient	•	out Del Time	lay																
	[µA]		[mA]		[mA]	ILEAK [nA]																		Δ-VDET/ΔTopt [ppm/°C]		[ms]	
Cond.	Min.	Cond.	Min.	Cond.	Min.	Cond.	Max.	Тур.	Cond.	Min.	Max.																
		VDD= 0.6V VDS= 0.5V	0.020							80	130																
		VDD= 1.0V VDS= 0.5V	0.400							70	150																
VDD= 0.55V VDS= 0.05V	7	VDD= 1.5V VDS= 0.5V	1.000	VDD= 4.5V VDS= -2.1V	0.650	VDD= 6.0V VDS= 7.0V	80	±30	CD= 0.022µF VDD= -VDET -0.1V ↓ -VDET																		
		VDD= 3.0V VDS= 0.5V	2.400	V _{DD=} 6.0V					×1.1V *Note2	85 75	115 135																
				VDS= -2.1V	0.900																						

*Note2) 1. In the case of CMOS output type:

When the voltage is forced from $(-V_{DET})-0.1V$ to $(-V_{DET})\times1.1V$ pulse voltage is added to V_{DD} , time interval that the output voltage reaches $((-V_{DET})\times1.1V)/2$.

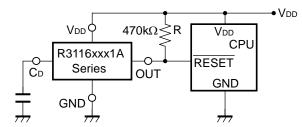
2. In the case of Nch Open Drain output type:

The output pin is pulled up to 5.0V through $470k\Omega$, and when the voltage is forced from (-V_{DET})-0.1V to (-V_{DET})×1.1V pulse voltage is added to V_{DD}, time interval that the output voltage reaches 2.5V.

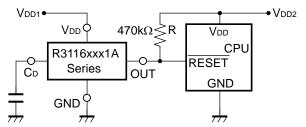
TYPICAL APPLICATION

• R3116xxx1A CPU Reset Circuit 1 (Nch Open Drain Output)

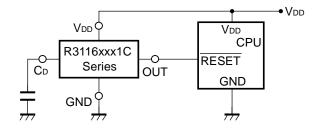
Case1. Input Voltage to R3116xxx1A is equal to Input Voltage to CPU



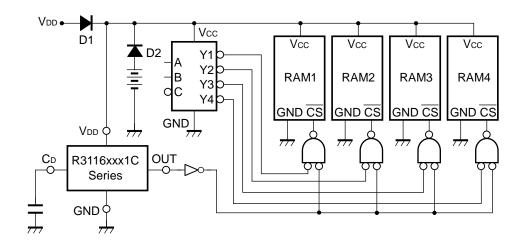
Case2. Input Voltage to R3116xxx1A is unequal to Input Voltage to CPU



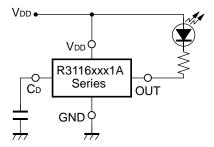
• R3116xxx1C CPU Reset Circuit 2 (CMOS Output)



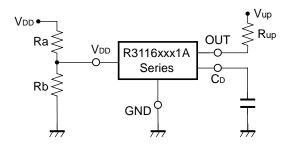
• Memory Back-up Circuit



Voltage level Indicator Circuit (lighted when the power runs out)
 (Nch Open Drain Output)



 Detector Threshold Adjustable Circuit 1 (Nch Open Drain Output)

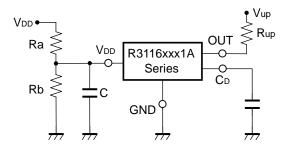


Adjustable Detector Threshold=(-VDET)×(Ra+Rb)/Rb

Hysteresis Voltage=(VHYS)×(Ra+Rb)/Rb

- *1) To prevent oscillation, set Ra $\leq 1k\Omega$, Rb $\leq 100\Omega$.
- *2) If the value of Ra is set excessively large, voltage drop may occur caused by the supply current of IC itself, and detector threshold and hysteresis voltage may vary.
- *3) If Vup and VDD are connected, the voltage dropdown caused by Rup, may cause difference in the hysteresis voltage.

 Detector Threshold Adjustable Circuit 2 (Nch Open Drain Output)

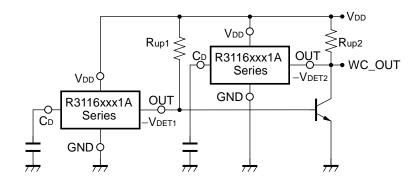


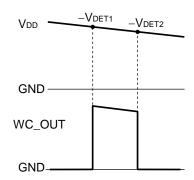
Adjustable Detector Threshold=(-VDET)×(Ra+Rb)/Rb

Hysteresis Voltage=(V_{HYS})×(Ra+Rb)/Rb

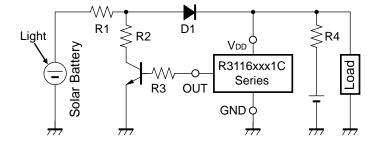
- *1) To prevent oscillation, set Ra \leq 10k Ω , Rb \leq 1k Ω , C \geq 1 μ F.
- *2) If the value of Ra is set excessively large, voltage drop may occur caused by the supply current of IC itself, and detector threshold and hysteresis voltage may vary.
- *3) If Vup and VDD are connected, the voltage dropdown caused by Rup, may cause difference in the hysteresis voltage.
- *4) If the value of Ra, Rb and C are set excessively large, the delay of the start-up may become too long.

Window Comparator Circuit (Nch Open Drain Output)





• Over-charge Preventing Circuit



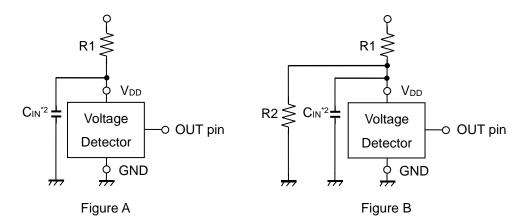
TECHNICAL NOTES

When connecting resistors to the device's input pin

When connecting a resistor (R1) to an input of this device, the input voltage decreases by [Device's Consumption Current] x [Resistance Value] only. And, the cross conduction current*1, which occurs when changing from the detecting state to the release state, is decreased the input voltage by [Cross Conduction Current] x [Resistance Value] only. And then, this device will enter the re-detecting state if the input voltage reduction is larger than the difference between the detector voltage and the released voltage.

When the input resistance value is large and the VDD is gone up at mildly in the vicinity of the released voltage, repeating the above operation may result in the occurrence of output.

As shown in Figure A/B, set R1 to become $100k\Omega$ or less as a guide, and connect C_{IN} of $0.1\mu F$ and more to between the input pin and GND. Besides, make evaluations including temperature properties under the actual usage condition, with using the evaluation board like this way. As result, make sure that the cross conduction current has no problem.

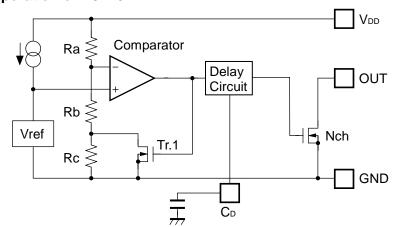


^{*1} In the CMOS output type, a charging current for OUT pin is included.

^{*2} Note the bias dependence of capacitors.

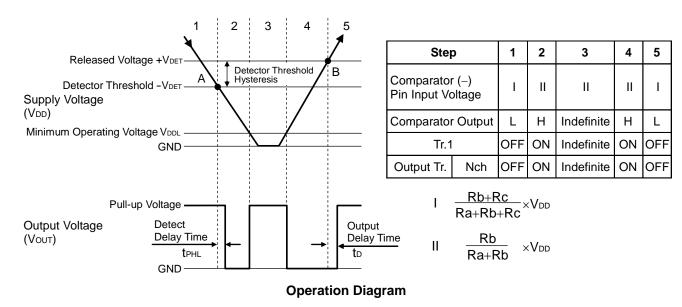
OPERATION

• Operation of R3116xxx1A



OUT pin should be pulled-up to VDD or an external voltage level.

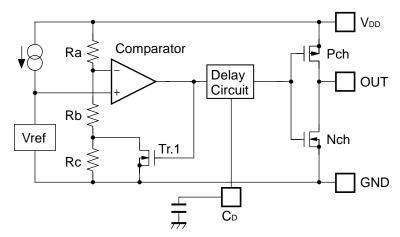
Block Diagram (R3116xxx1A)



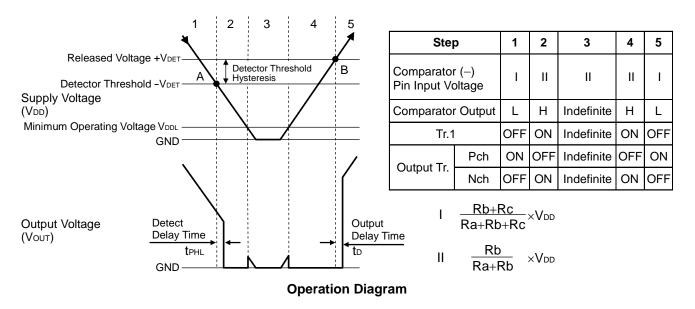
Explanation of operation

- Step 1. The output voltage is equal to the pull-up voltage.
- Step 2. At Point "A", Vref ≥ Vddx(Rb+Rc)/(Ra+Rb+Rc) is true, as a result, the output of comparator is reversed from "L" to "H", therefore the output voltage becomes the GND level. The voltage level of Point A means a detector threshold voltage (-Vdet).
- Step 3. When the supply voltage is lower than the minimum operating voltage, the operation of the output transistor becomes indefinite. The output voltage is equal to the pull-up voltage.
- Step 4. The output voltage is equal to the GND level.
- Step 5. At Point "B", Vref ≤ VDD×Rb/(Ra+Rb) is true, as a result, the output of comparator is reversed from "H" to "L", then the output voltage is equal to the pull-up voltage. The voltage level of Point B means a released voltage (+VDET).
- *) The difference between a released voltage and a detector threshold voltage is a detector threshold hysteresis.

Operation of R3116xxx1C



Block Diagram (R3116xxx1C)

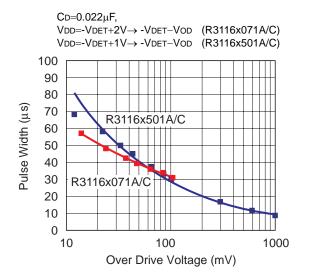


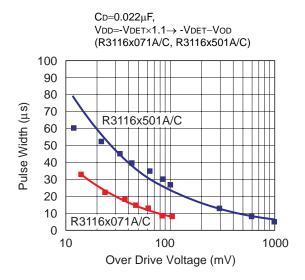
Explanation of operation

- Step 1. The output voltage is equal to the supply voltage (VDD).
- Step 2. At Point "A", Vref ≥ V_{DD}×(Rb+Rc)/(Ra+Rb+Rc) is true, as a result, the output of comparator is reversed from "L" to "H", therefore the output voltage becomes the GND level. The voltage level of Point A means a detector threshold voltage (-V_{DET}).
- Step 3. When the supply voltage is lower than the minimum operating voltage, the operation of the output transistor becomes indefinite.
- Step 4. The output voltage is equal to the GND level.
- Step 5. At Point "B", Vref \leq V_{DD}×Rb/(Ra+Rb) is true, as a result, the output of comparator is reversed from "H" to "L", then the output voltage is equal to the supply voltage (V_{DD}). The voltage level of Point B means a released voltage (+V_{DET}).
- *) The difference between a released voltage and a detector threshold voltage is a detector threshold hysteresis.

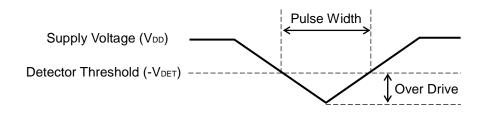
Detector Operation vs. glitch input voltage to the VDD pin

When the R3116x is at released, if the pulse voltage which the detector threshold or lower voltage, the graph below means that the relation between pulse width and the amplitude of the swing to keep the released state for the R3116x.





*Vop: Over Drive Voltage



VDD Input Waveform

This graph shows the maximum pulse conditions to keep the released voltage. If the pulse with larger amplitude or wider width than the graph above, is input to V_{DD} pin, the reset signal may be output.

PACKAGE INFORMATION

POWER DISSIPATION (DFN(PLP)1010-4)

Power Dissipation (P_D) depends on conditions of mounting on board. This specification is based on the measurement at the condition below:

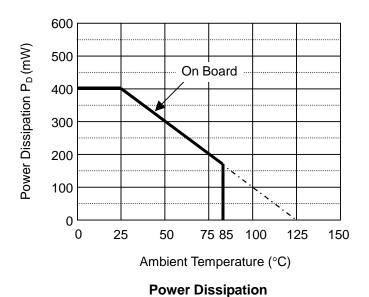
Measurement Conditions

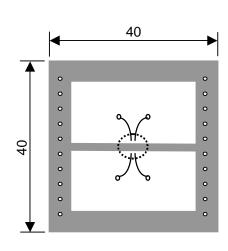
ioadaromoni odnamono		
	Standard Test Land Pattern	
Environment	Mounting on Board (Wind velocity=0m/s)	
Board Material	Glass cloth epoxy plastic (Double sided)	
Board Dimensions	40mm*40mm*1.6mm	
Copper Ratio	Top side: Approx. 50%, Back side: Approx. 50%	
Through-holes	φ 0.54mm * 24pcs	

Measurement Result:

(Ta=25°C, Timax=125°C)

	Standard Test Land Pattern	
Power Dissipation	400mW	
Thermal Resistance	θja = (125-25°C)/0.4W = 250°C/W	
	θjc = 67 °C/W	

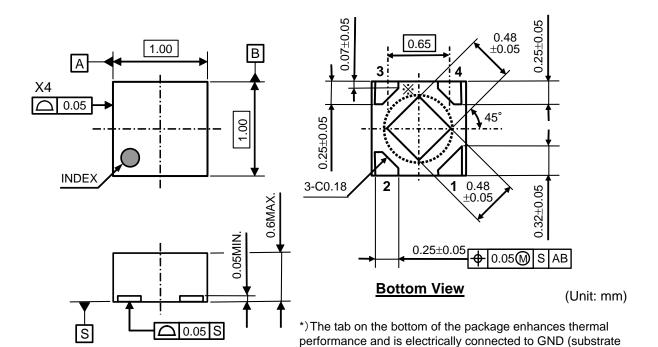




Measurement Board Pattern

IC Mount Area (Unit : mm)

PACKAGE DIMENSIONS (DFN(PLP)1010-4)

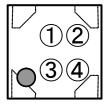


level). It is recommended that the tab be connected to the ground plane on the board, or otherwise be left floating.

MARK SPECIFICATION (DFN(PLP)1010-4)

①②: Product Code ... Refer to MARK SPECIFICATION TABLE

34: Lot Number ... Alphanumeric Serial Number



NO.EA-161-140819

MARK SPECIFICATION TABLE (DFN(PLP)1010-4)

R3116Kxx1A

TO T		
Product Name	02	V _{SET}
R3116K071A	HA	0.7V
R3116K081A	HB	0.8V
R3116K091A	HC	0.9V
R3116K101A	HD	1.0V
R3116K111A	HE	1.1V
R3116K121A	HF	1.2V
R3116K131A	HG	1.3V
R3116K141A	HH	1.4V
R3116K151A	HJ	1.5V
R3116K161A	HK	1.6V
R3116K171A	HL	1.7V
R3116K181A	HM	1.8V
R3116K191A	HN	1.9V
R3116K201A	HP	2.0V
R3116K211A	HQ	2.1V
R3116K221A	HR	2.2V
R3116K231A	HS	2.3V
R3116K241A	HT	2.4V
R3116K251A	HU	2.5V
R3116K261A	HV	2.6V
R3116K271A	HW	2.7V
R3116K281A	HX	2.8V
R3116K291A	HY	2.9V
R3116K301A	HZ	3.0V
R3116K311A	JA	3.1V
R3116K321A	JB	3.2V
R3116K331A	JC	3.3V
R3116K341A	JD	3.4V
R3116K351A	JE	3.5V
R3116K361A	JF	3.6V
R3116K371A	JG	3.7V
R3116K381A	JH	3.8V
R3116K391A	JJ	3.9V
R3116K401A	JK 	4.0V
R3116K411A	JL	4.1V
R3116K421A	JM	4.2V
R3116K431A	JN	4.3V
R3116K441A	JP	4.4V
R3116K451A	JQ	4.5V
R3116K461A	JR	4.6V
R3116K471A	J <u>S</u>	4.7V
R3116K481A	JT	4.8V
R3116K491A	JU	4.9V
R3116K501A	JV	5.0V

R3116Kxx1C

Product Name	00	V _{SET}
R3116K071C	KA	0.7V
R3116K081C	KB	0.8V
R3116K091C	KC	0.9V
R3116K101C	KD	1.0V
R3116K111C	KE	1.1V
R3116K121C	KF	1.2V
R3116K131C	KG	1.3V
R3116K141C	KH	1.4V
R3116K151C	KJ	1.5V
R3116K161C	KK	1.6V
R3116K171C	KL	1.7V
R3116K181C	KM	1.8V
R3116K191C	KN	1.9V
R3116K201C	KP	2.0V
R3116K211C	KQ	2.1V
R3116K221C	KR	2.2V
R3116K231C	KS	2.3V
R3116K241C	KT	2.4V
R3116K251C	KU	2.5V
R3116K261C	KV	2.6V
R3116K271C	KW	2.7V
R3116K281C	KX	2.8V
R3116K291C	KY	2.9V
R3116K301C	KZ	3.0V
R3116K311C	LA	3.1V
R3116K321C	LB	3.2V
R3116K331C	LC	3.3V
R3116K341C	LD	3.4V
R3116K351C	LE	3.5V
R3116K361C	LF	3.6V
R3116K371C	LG	3.7V
R3116K381C	LH	3.8V
R3116K391C	LJ	3.9V
R3116K401C	LK	4.0V
R3116K411C	LL	4.1V
R3116K421C	LM	4.2V
R3116K431C	LN	4.3V
R3116K441C	LP	4.4V
R3116K451C	LQ	4.5V
R3116K461C	LR	4.6V
R3116K471C	LS	4.7V
R3116K481C	LT	4.8V
R3116K491C	LU	4.9V
R3116K501C	LV	5.0V

POWER DISSIPATION (SC-82AB)

Power Dissipation (P_D) depends on conditions of mounting on board. This specification is based on the measurement at the condition below;

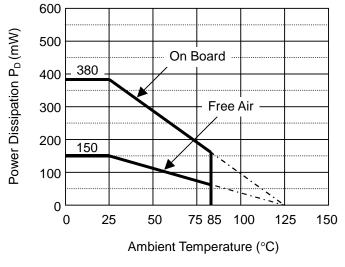
* Measurement Conditions

	Standard Land Pattern	
Environment	Mounting on Board (Wind velocity=0m/s)	
Board Material	Glass cloth epoxy plastic (Double Layers)	
Board Dimensions	40mm × 40mm × 1.6mm	
Copper Ratio	Top side: Approx. 50%, Back side: Approx. 50%	
Through-hole	φ0.5mm × 44pcs	

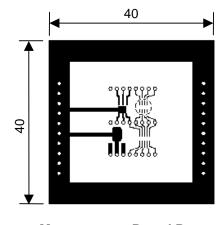
* Measurement Result

(Ta=25°C, Tjmax=125°C)

	Standard Land Pattern	Free Air
Power Dissipation	380mW	150mW
Thermal Resistance	θja = (125-25°C)/0.38W = 263°C/W	667°C/W



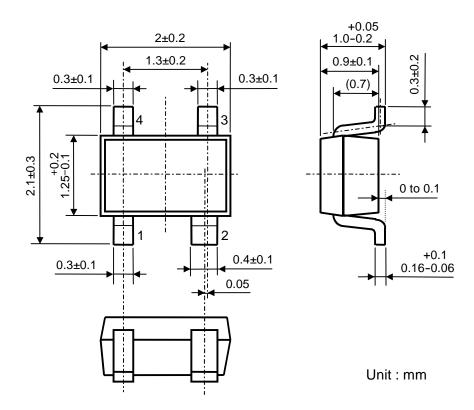
Power Dissipation



Measurement Board Pattern

IC Mount Area (Unit : mm)

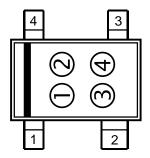
PACKAGE DIMENSIONS (SC-82AB)



MARK SPECIFICATION (SC-82AB)

①②: Product Code ... Refer to MARK SPECIFICATION TABLE

 $\ensuremath{\mathfrak{3}}\ensuremath{\mathfrak{4}};$ Lot Number ... Alphanumeric Serial Number



MARK SPECIFICATION TABLE (SC-82AB)

R3116Qxx1A

Product Name	0 2	V
		V _{SET}
R3116Q071A	L O	0.7V
R3116Q081A	L1	0.8V
R3116Q091A	L2	0.9V
R3116Q101A	L3	1.0V
R3116Q111A	L 4	1.1V
R3116Q121A	L5	1.2V
R3116Q131A	L6	1.3V
R3116Q141A	L7	1.4V
R3116Q151A	L8	1.5V
R3116Q161A	L9	1.6V
R3116Q171A	M 0	1.7V
R3116Q181A	M 1	1.8V
R3116Q191A	M 2	1.9V
R3116Q201A	M 3	2.0V
R3116Q211A	M 4	2.1V
R3116Q221A	M 5	2.2V
R3116Q231A	M 6	2.3V
R3116Q241A	M 7	2.4V
R3116Q251A	M 8	2.5V
R3116Q261A	M 9	2.6V
R3116Q271A	N O	2.7V
R3116Q281A	N 1	2.8V
R3116Q291A	N 2	2.9V
R3116Q301A	N 3	3.0V
R3116Q311A	N 4	3.1V
R3116Q321A	N 5	3.2V
R3116Q331A	N 6	3.3V
R3116Q341A	N 7	3.4V
R3116Q351A	N 8	3.5V
R3116Q361A	N 9	3.6V
R3116Q371A	P 0	3.7V
R3116Q381A	P 1	3.8V
R3116Q391A	P 2	3.9V
R3116Q401A	Р3	4.0V
R3116Q411A	P 4	4.1V
R3116Q421A	P 5	4.2V
R3116Q431A	P 6	4.3V
R3116Q441A	P 7	4.4V
R3116Q451A	P 8	4.5V
R3116Q461A	P 9	4.6V
R3116Q471A	Q 0	4.7V
R3116Q481A	Q 1	4.8V
R3116Q491A	Q 2	4.9V
R3116Q501A	Q 3	5.0V

R3116Qxx1C

KSTIOQXXIC		
Product Name	0 2	V _{SET}
R3116Q071C	R 0	0.7V
R3116Q081C	R 1	V8.0
R3116Q091C	R 2	0.9V
R3116Q101C	R 3	1.0V
R3116Q111C	R 4	1.1V
R3116Q121C	R 5	1.2V
R3116Q131C	R 6	1.3V
R3116Q141C	R 7	1.4V
R3116Q151C	R 8	1.5V
R3116Q161C	R 9	1.6V
R3116Q171C	S 0	1.7V
R3116Q181C	S 1	1.8V
R3116Q191C	S 2	1.9V
R3116Q201C	S 3	2.0V
R3116Q211C	S 4	2.1V
R3116Q221C	S 5	2.2V
R3116Q231C	\$5 \$6 \$7	2.3V
R3116Q241C	S 7	2.4V
R3116Q251C	S 8	2.2V 2.3V 2.4V 2.5V
R3116Q261C	S 9	2.6V
R3116Q271C	Τ0	2.7V
R3116Q281C	T 1	2.8V
R3116Q291C	T 2	2.9V
R3116Q301C	T 3	3.0V
R3116Q311C	T 4	3.1V
R3116Q321C	T 5	3.2V
R3116Q331C	T 6	3.3V
R3116Q341C	T 7	3.4V
R3116Q351C	T 8	3.5V
R3116Q361C	Т9	3.6V
R3116Q371C	U 0	3.7V
R3116Q381C	U 1	3.8V
R3116Q391C	U 2	3.9V
R3116Q401C	U 3	4.0V
R3116Q411C	U 4	4.1V
R3116Q421C	U 5	4.2V
R3116Q431C	U 6	4.3V
R3116Q441C	U 7	4.4V
R3116Q451C	U 8	4.5V
R3116Q461C	U 9	4.6V
R3116Q471C	V 0	4.7V
R3116Q481C	V 1	4.8V
R3116Q491C	V 2	4.9V
R3116Q501C	V 3	5.0V

NO.EA-161-140819

POWER DISSIPATION (SOT-23-5)

Power Dissipation (P_D) depends on conditions of mounting on board. This specification is based on the measurement at the condition below:

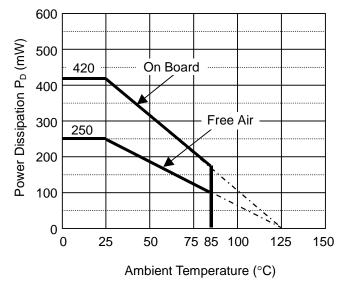
(Power Dissipation (SOT-23-5) is substitution of SOT-23-6.)

* Measurement Conditions

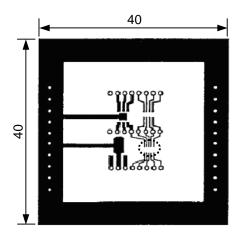
	Standard Test Land Pattern	
Environment	Mounting on Board (Wind velocity=0m/s)	
Board Material	Glass cloth epoxy plastic (Double sided)	
Board Dimensions	40mm*40mm*1.6mm	
Copper Ratio	Top side: Approx. 50%, Back side: Approx. 50%	
Through-holes	φ 0.5mm * 44pcs	

* Measurement Result:(Ta=25°C, Timax=125°C)

		(== = , , = = = ,
	Standard Land Pattern	Free Air
Power Dissipation	420mW	250mW
Thermal Resistance	θja = (125-25°C)/0.42W= 238°C/W	400°C/W



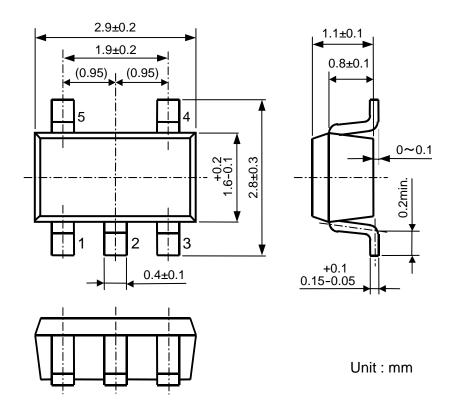
Power Dissipation



Measurement Board Pattern

IC Mount Area (Unit: mm)

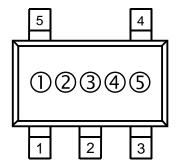
PACKAGE DIMENSIONS (SOT-23-5)



MARK SPECIFICATION (SOT-23-5)

①②③: Product Code ... Refer to MARK SPECIFICATION TABLE

④⑤: Lot Number ... Alphanumeric Serial Number



NO.EA-161-140819

MARK SPECIFICATION TABLE (SOT-23-5)

R3116Nxx1A

Product Name	023	V
		V _{SET}
R3116N071A	DOA	0.7V
R3116N081A	D 0 B	V8.0
R3116N091A	DOC	0.9V
R3116N101A	D 0 D	1.0V
R3116N111A	D0E	1.1V
R3116N121A	D0F	1.2V
R3116N131A	DOG	1.3V
R3116N141A	D0H	1.4V
R3116N151A	DOJ	1.5V
R3116N161A	D0K	1.6V
R3116N171A	D 0 L	1.7V
R3116N181A	D 0 M	1.8V
R3116N191A	DON	1.9V
R3116N201A	D 0 P	2.0V
R3116N211A	D 0 Q	2.1V
R3116N221A	D0R	2.2V
R3116N231A	DOS	2.3V
R3116N241A	DOT	2.4V
R3116N251A	DOU	2.5V
R3116N261A	DOV	2.6V
R3116N271A	D 0 W	2.7V
R3116N281A	DOX	2.8V
R3116N291A	D0Y	2.9V
R3116N301A	DOZ	3.0V
R3116N311A	E 0 A	3.1V
R3116N321A	E 0 B	3.2V
R3116N331A	E 0 C	3.3V
R3116N341A	E 0 D	3.4V
R3116N351A	E 0 E	3.5V
R3116N361A	E 0 F	3.6V
R3116N371A	E 0 G	3.7V
R3116N381A	E 0 H	3.8V
R3116N391A	E 0 J	3.9V
R3116N401A	E 0 K	4.0V
R3116N411A	EOL	4.1V
R3116N421A	E 0 M	4.2V
R3116N431A	E 0 N	4.3V
R3116N441A	E 0 P	4.4V
R3116N451A	E 0 Q	4.5V
R3116N461A	E 0 R	4.6V
R3116N471A	E 0 S	4.7V
R3116N481A	E 0 T	4.8V
R3116N491A	E 0 U	4.9V
R3116N501A	E 0 V	5.0V

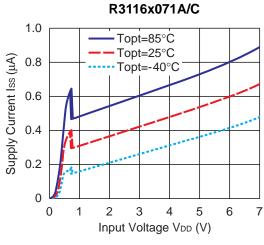
R3116Nxx1C

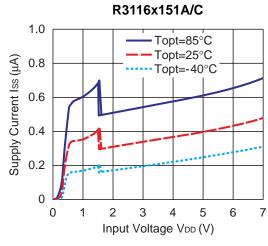
Product Name	023	V _{SET}
R3116N071C	D1A	0.7V
R3116N081C	D1B	0.8V
R3116N091C	D1C	0.9V
R3116N101C	D1D	1.0V
R3116N111C	D1E	1.1V
R3116N121C	D1F	1.2V
R3116N131C	D1G	1.3V
R3116N141C	D1H	1.4V
R3116N151C	D1J	1.5V
R3116N161C	D1K	1.6V
R3116N171C	D1L	1.7V
R3116N181C	D1M	1.8V
R3116N191C	D 1 N	1.9V
R3116N201C	D1P	2.0V
R3116N211C	D1Q	2.1V
R3116N221C	D1R	2.2V 2.3V
R3116N231C	D1S	2.3V
R3116N241C	D1T	2.4V
R3116N251C	D1U	2.5V
R3116N261C	D1V	2.6V
R3116N271C	D1W	2.7V
R3116N281C	D1X	2.8V
R3116N291C	D1Y	2.9V
R3116N301C	D1Z	3.0V
R3116N311C	E1A	3.1V
R3116N321C	E1B	3.2V
R3116N331C	E1C	3.3V
R3116N341C	E1D	3.4V
R3116N351C	E1E	3.5V
R3116N361C	E1F	3.6V
R3116N371C	E1G	3.7V
R3116N381C	E1H	3.8V
R3116N391C	E 1 J	3.9V
R3116N401C	E1K	4.0V
R3116N411C	E1L	4.1V
R3116N421C	E 1 M	4.2V
R3116N431C	E 1 N	4.3V
R3116N441C	E 1 P	4.4V
R3116N451C	E1Q	4.5V
R3116N461C	E1R	4.6V
R3116N471C	E1S	4.7V
R3116N481C	E1T	4.8V
R3116N491C	E 1 U	4.9V
R3116N501C	E 1 V	5.0V

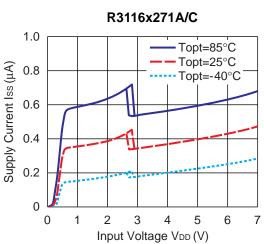
TYPICAL CHARACTERISTICS

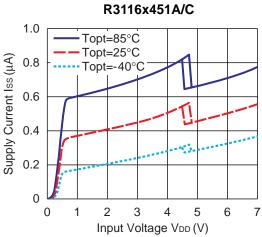
Note: Typical Characteristics are intended to be used as reference data; they are not guaranteed.

1) Supply Current vs. Input Voltage

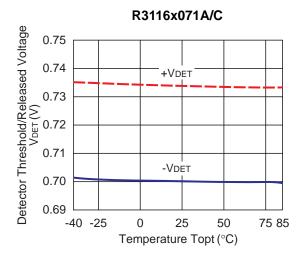


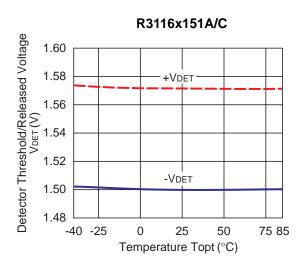




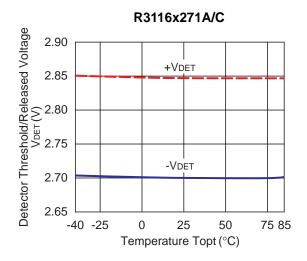


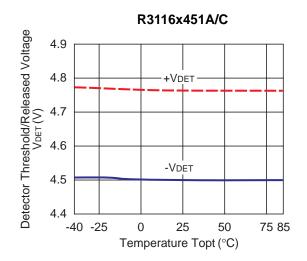
2) Detector Threshold vs. Temperature



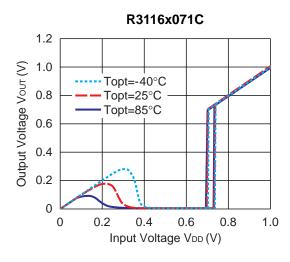


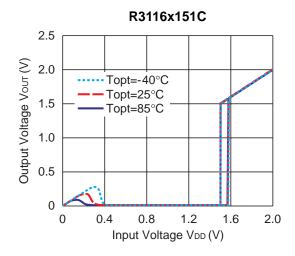
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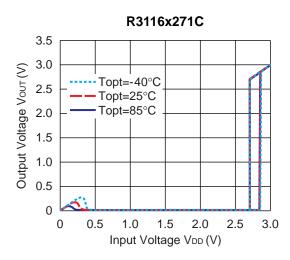


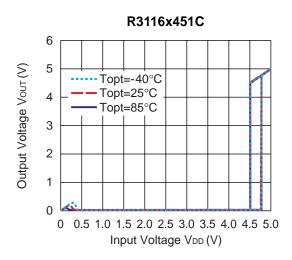


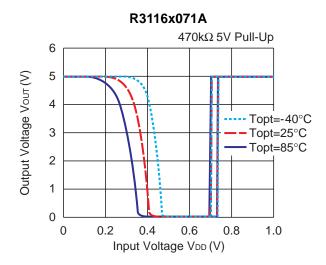
3) Output Voltage vs. Input Voltage

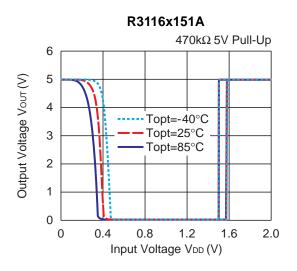


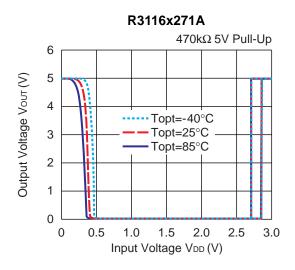


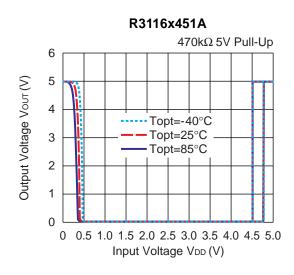




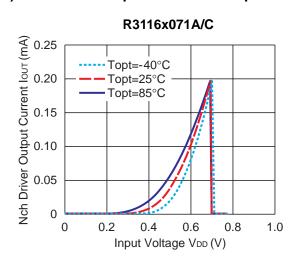


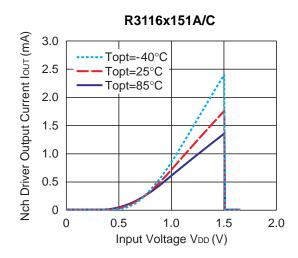




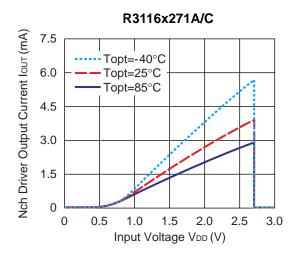


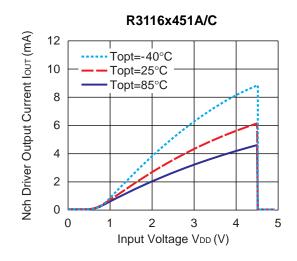
4) Nch Driver Output Current vs. Input Voltage (VDS=0.5V)



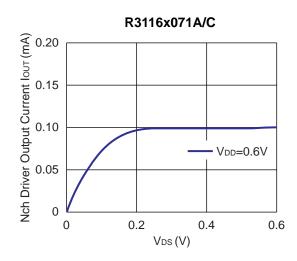


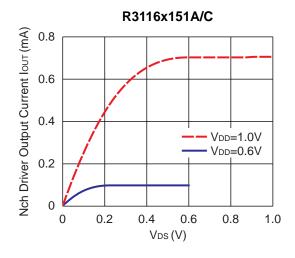
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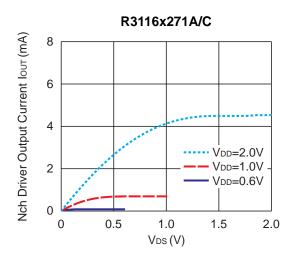


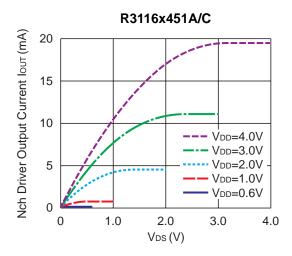


5) Nch Driver Output Current vs. VDS

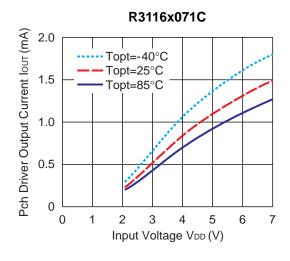


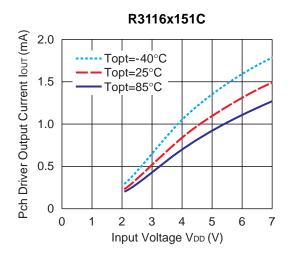


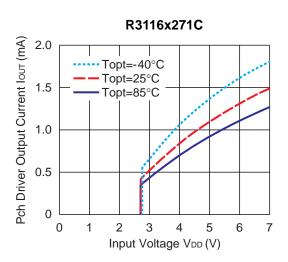


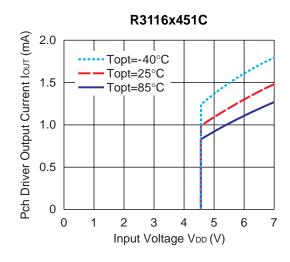


6) Pch Driver Output Current vs. Input Voltage (VDS=-2.1V)

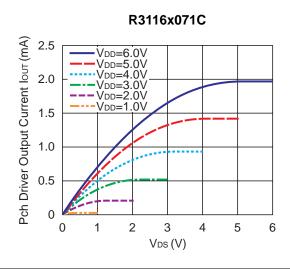


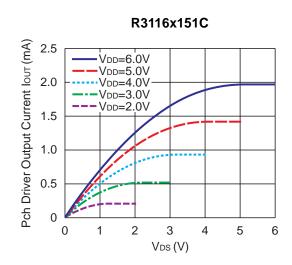




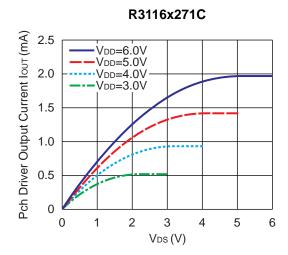


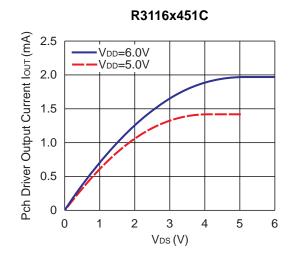
7) Pch Driver Output Current vs. VDS



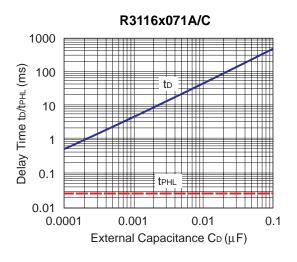


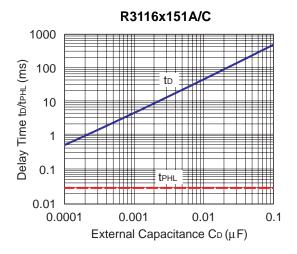
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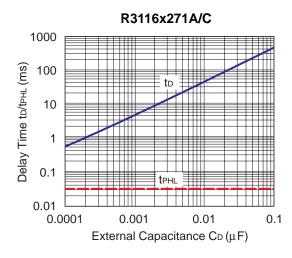


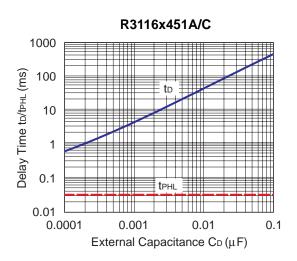


8) Output Delay Time vs. External Capacitance

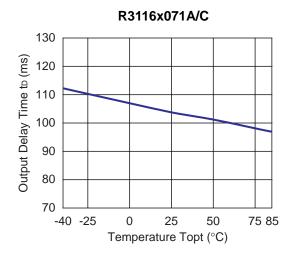


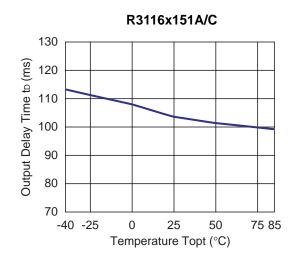


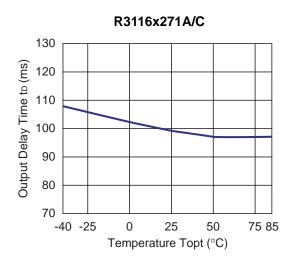


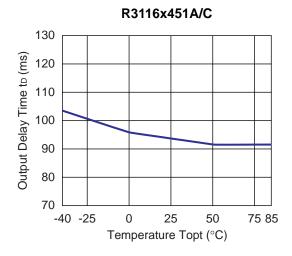


9) Output Delay Time vs. Temperature (CD=22nF)











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